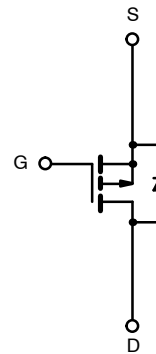
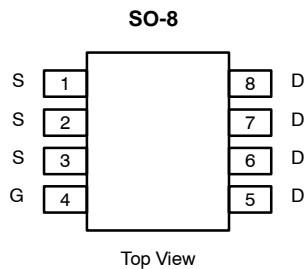




P-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY		
V_{DS} (V)	$r_{DS(on)}$ (Ω)	I_D (A)
-20	0.040 @ $V_{GS} = -4.5$ V	-6.3
	0.055 @ $V_{GS} = -2.5$ V	-5.1



P-Channel MOSFET

Ordering Information: Si9434BDY—E3 (Lead (Pb)-Free)
Si9434BDY-T1—E3 (Lead (Pb)-Free with Tape and Reel)

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)					
Parameter	Symbol	10 secs	Steady State	Unit	
Drain-Source Voltage	V_{DS}	-20		V	
Gate-Source Voltage	V_{GS}	± 8			
Continuous Drain Current ($T_J = 150^\circ\text{C}$) ^a	I_D	$T_A = 25^\circ\text{C}$	-6.3	-4.5	A
		$T_A = 70^\circ\text{C}$	-5.0	-3.6	
Pulsed Drain Current	I_{DM}	-20			
Continuous Source Current (Diode Conduction) ^a	I_S	-2.3	-1.2		
Maximum Power Dissipation ^a	P_D	$T_A = 25^\circ\text{C}$	2.5	1.3	W
		$T_A = 70^\circ\text{C}$	1.6	0.8	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55 to 150		$^\circ\text{C}$	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^a	R_{thJA}	$t \leq 10$ sec	45	50	$^\circ\text{C/W}$
		Steady State	80	95	
Maximum Junction-to-Foot (Drain)	R_{thJF}	20	24		

Notes
a. Surface Mounted on FR4 Board, $t \leq 10$ sec.

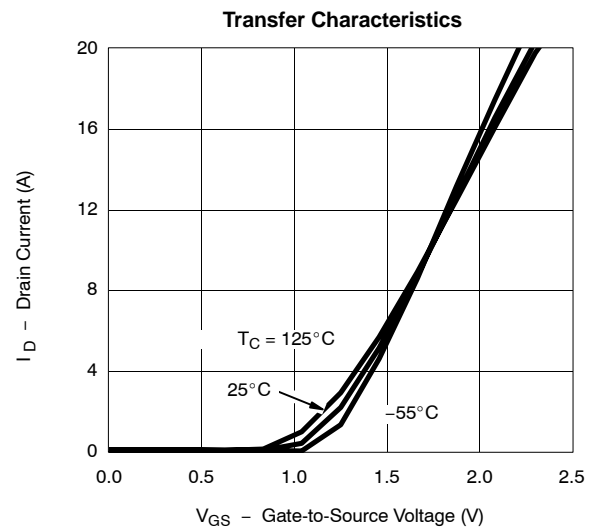
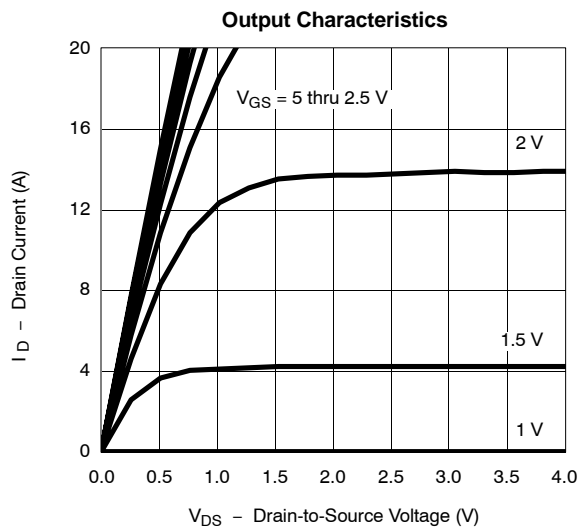


SPECIFICATIONS (T _J = 25 °C UNLESS OTHERWISE NOTED)						
Parameter	Symbol	Test Condition	Min	Typ ^a	Max	Unit
Static						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250 μA	-0.45		-1.5	V
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ±8 V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = -20 V, V _{GS} = 0 V			-1	μA
		V _{DS} = -20 V, V _{GS} = 0 V, T _J = 70 °C			-5	
On-State Drain Current ^b	I _{D(on)}	V _{DS} ≤ -5 V, V _{GS} = -4.5 V	-20			A
		V _{DS} ≤ -5 V, V _{GS} = -2.5 V	-5			
Drain-Source On-State Resistance ^b	r _{DS(on)}	V _{GS} = -4.5 V, I _D = -6.3 A		0.033	0.040	Ω
		V _{GS} = -2.5 V, I _D = -5.1 A		0.044	0.055	
Forward Transconductance ^b	g _{fs}	V _{DS} = -9 V, I _D = -6.3 A		10		S
Diode Forward Voltage ^b	V _{SD}	I _S = -2.3 A, V _{GS} = 0 V		-0.8	-1.2	V
Dynamic^a						
Total Gate Charge	Q _g	V _{DS} = -10 V, V _{GS} = -4.5 V, I _D = -6.3 A		12	18	nC
Gate-Source Charge	Q _{gs}			1.7		
Gate-Drain Charge	Q _{gd}			3.5		
Gate Resistance	R _g			7		Ω
Turn-On Delay Time	t _{d(on)}	V _{DD} = -10 V, R _L = 10 Ω I _D ≅ -1 A, V _{GEN} = -4.5 V, R _g = 6 Ω		15	25	ns
Rise Time	t _r			45	75	
Turn-Off Delay Time	t _{d(off)}			80	130	
Fall Time	t _f			60	100	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = -2.3 A, di/dt = 100 A/μs		40	70	

Notes

- a. For design aid only; not subject to production testing.
- b. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2%.

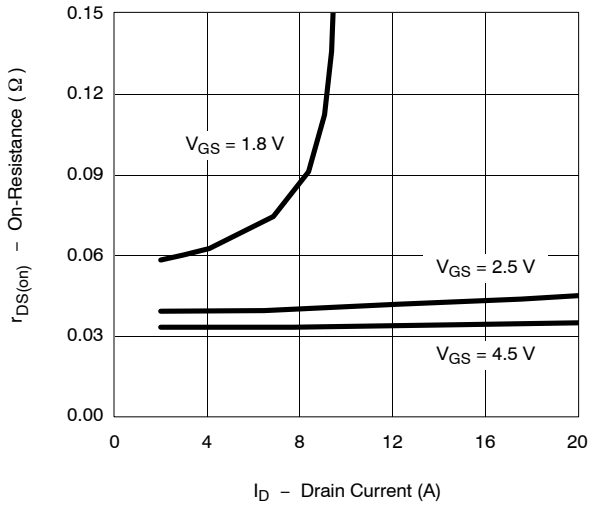
TYPICAL CHARACTERISTICS (25 °C UNLESS NOTED)



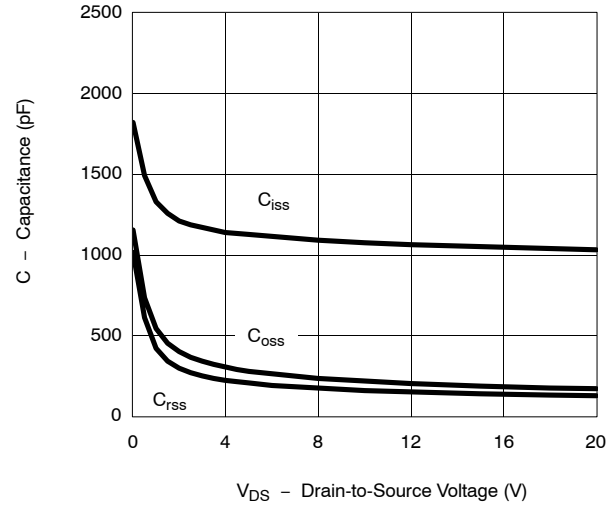


TYPICAL CHARACTERISTICS (25 °C UNLESS NOTED)

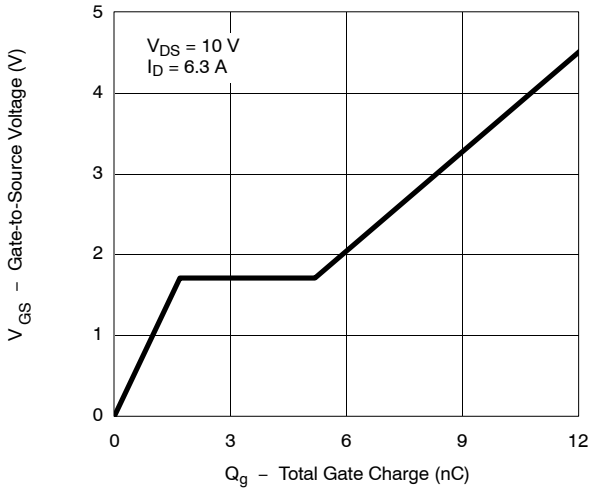
On-Resistance vs. Drain Current



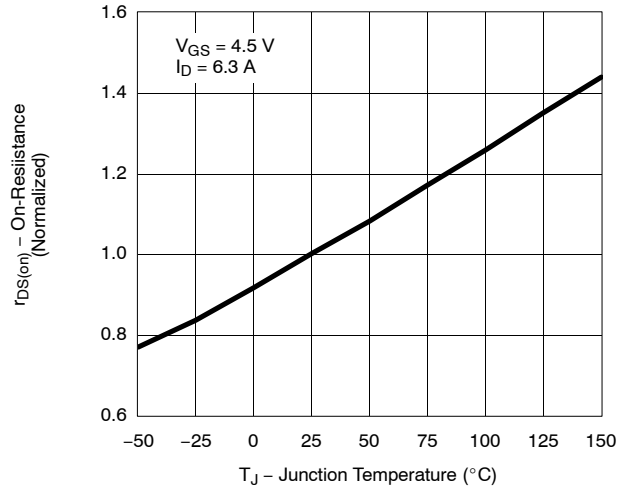
Capacitance



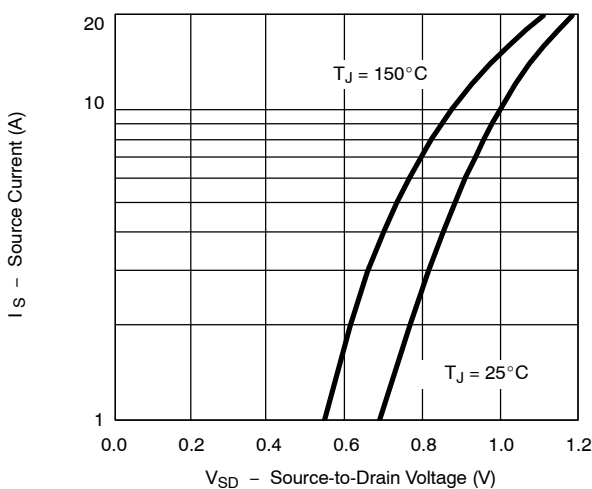
Gate Charge



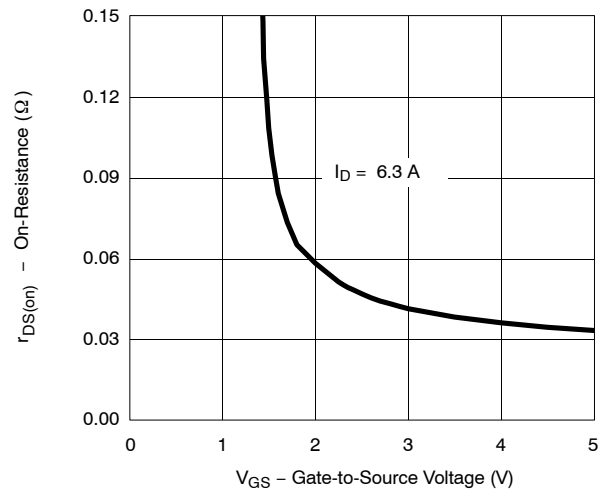
On-Resistance vs. Junction Temperature



Source-Drain Diode Forward Voltage

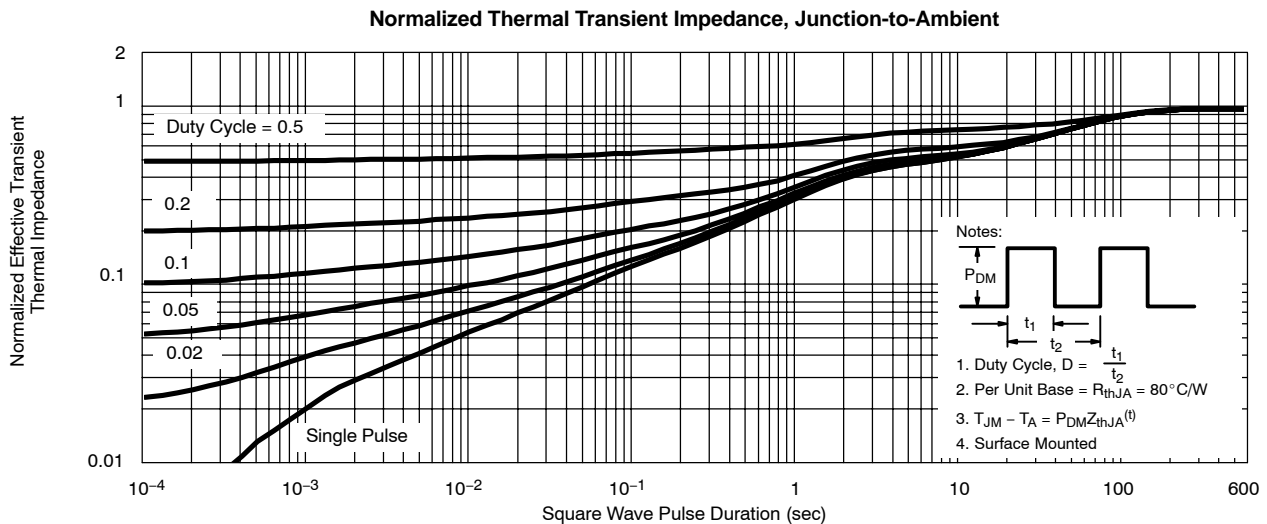
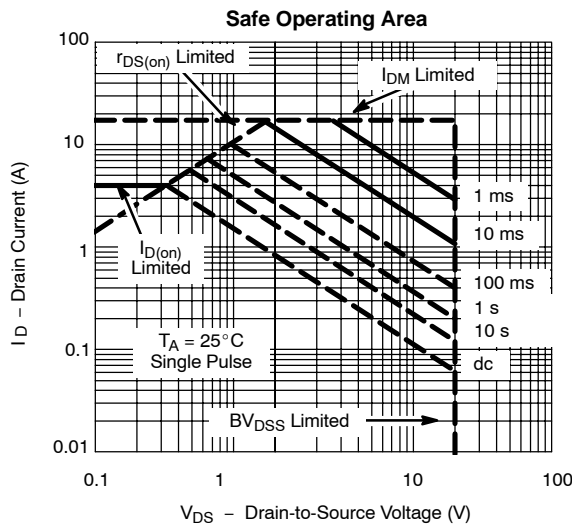
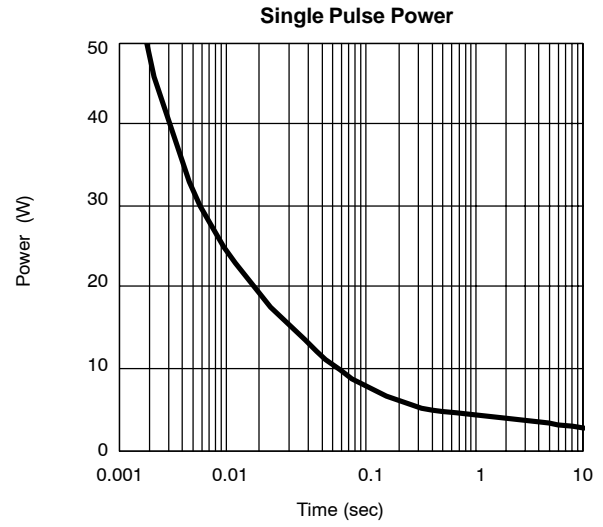
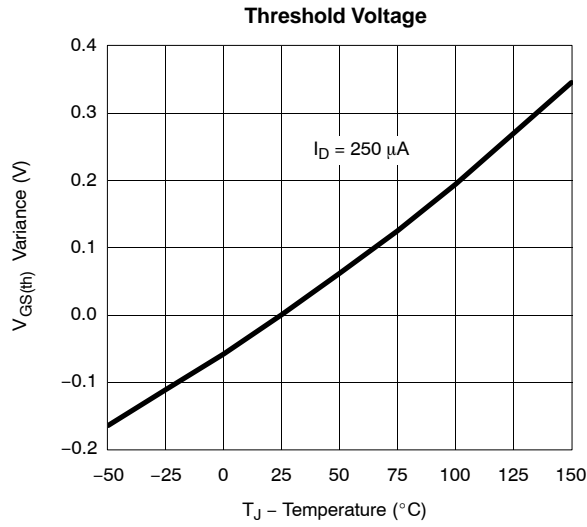


On-Resistance vs. Gate-to-Source Voltage



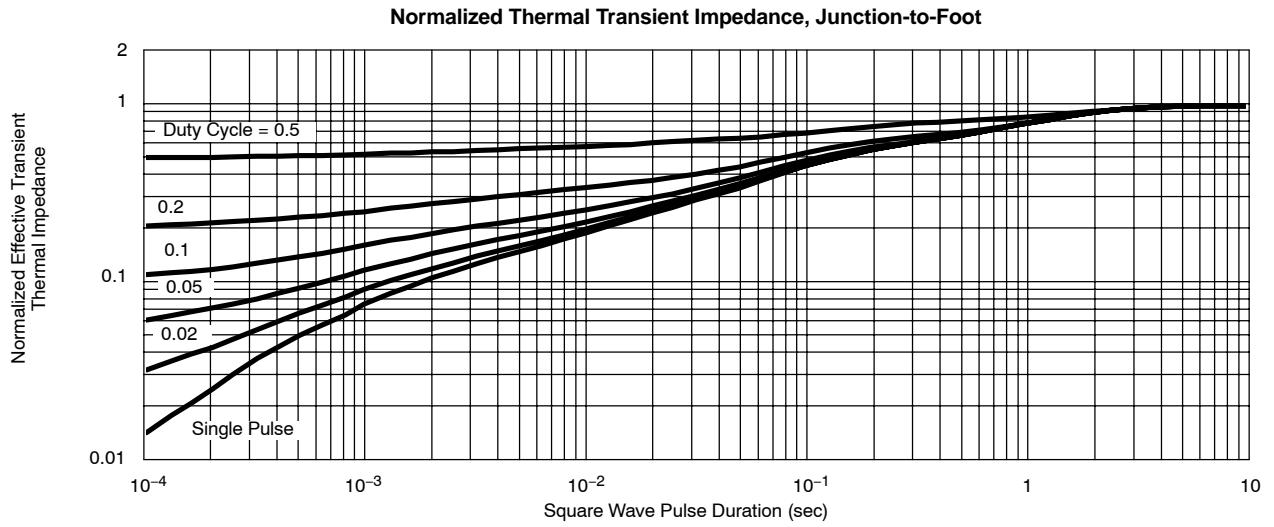


TYPICAL CHARACTERISTICS (25 °C UNLESS NOTED)





TYPICAL CHARACTERISTICS (25 °C UNLESS NOTED)





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